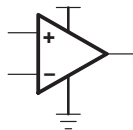


FAMILY OF LOW-POWER WIDE BANDWIDTH SINGLE SUPPLY OPERATIONAL AMPLIFIERS WITH AND WITHOUT SHUTDOWN

FEATURES

- Rail-To-Rail Output
- V_{ICR} Includes Ground
- Gain-Bandwidth Product . . . 9 MHz
- Supply Current . . . 730 $\mu\text{A}/\text{Channel}$
- Single, Duals, and Quad Versions
- Ultralow Power Down Mode
 $I_{DD}(\text{SHDN}) = 4 \mu\text{A}/\text{Channel}$
- Specified Temperature Range
 -40°C to 125°C . . . Industrial Grade
- Supply Voltage Range . . . 2.7 V to 5.5 V
- Ultrasmall Packaging
5 or 6 Pin SOT-23 (TLV2630/1)
8 or 10 Pin MSOP (TLV2632/3)
- Universal Op-Amp EVM (See SLOU060
for More Information)

Operational Amplifier



DESCRIPTION

The TLV263x single supply operational amplifiers provide rail-to-rail output with an input range that includes ground. The TLV263x takes the minimum operating supply voltage down to 2.7 V over the extended industrial temperature range (-40°C to 125°C) while adding the rail-to-rail output swing feature. The TLV263x also provides a 9 MHz gain-bandwidth product from only 730 μA of supply current. The maximum recommended supply voltage is 5.5 V, which, when coupled with a 2.7-V minimum, allows the devices to be operated from lithium ion cells.

The combination of wide bandwidth, low noise, and low distortion makes it ideal for high speed and high resolution data converter applications. The ground input range allows it to directly interface to ground rail referred systems.

All members are available in PDIP and SOIC with the singles in the small SOT-23 package, duals in the MSOP, and quads in the TSSOP package.

The 2.7-V operation makes it compatible with Li-Ion powered systems and the operating supply voltage range of many micro-power microcontrollers available today including TI's MSP430.

AMPLIFIER SELECTION TABLE

| DEVICE | V_{DD} [V] | I_{DD}/ch [μA] | V_{ICR} [V] | GBW [MHz] | SLEW RATE [V/ μs] | V_n , 1 kHz [nV/ $\sqrt{\text{Hz}}$] | I_O [mA] |
|----------------|-----------------|---|---------------------------------------|--------------|----------------------------------|--|---------------|
| OPAx343 | 2.5–5.5 | 850 | -0.3 to $V_{DD} + 0.3$ | 5.5 | 6 | 25 | 40 |
| OPAx743 | 3.5–12 | 1100 | -0.1 to $V_{DD} + 0.1$ | 7 | 10 | 30 | 20 |
| TLV278x | 1.8–3.6 | 650 | -0.2 to $V_{DD} + 0.2$ | 8 | 5 | 9 | 10 |
| TLV263x | 2.7–5.5 | 730 | GND to $V_{DD} - 1$ | 9 | 9.5 | 50 | 28 |
| TLV262x | 2.7–5.5 | 750 | 1 V to $V_{DD} + 0.2$ | 11 | 10 | 27 | 28 |
| OPAx353 | 2.7–5.5 | 8000 | -0.1 to $V_{DD} + 0.1$ | 44 | 22 | 7 | 40 |



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

TLV2630, TLV2631
TLV2632, TLV2633
TLV2634, TLV2635

SLOS362A – JUNE 2001 – REVISED JANUARY 2005

PACKAGE/ORDERING INFORMATION(1)

| PRODUCT | PACKAGE | PACKAGE CODE | SYMBOL | SPECIFIED TEMPERATURE RANGE | ORDER NUMBER | TRANSPORT MEDIA |
|--------------------------------|----------|--------------|--------|-----------------------------|--------------------------------|-----------------------|
| Single with Shutdown | | | | | | |
| TLV2630ID | SOIC-8 | D | — | -40°C to 125°C | TLV2630ID TLV2630IDR | Tube Tape and Reel |
| TLV2630IDBV | SOT-23-6 | DBV | VAYI | | TLV2630IDBVR† TLV2630IDBVT‡ | Tape and Reel |
| TLV2630IP | DIP-8 | P | — | | TLV2630IP | Tube |
| Single without Shutdown | | | | | | |
| TLV2631ID | SOIC-8 | D | — | -40°C to 125°C | TLV2631ID TLV2631IDR | Tube Tape and Reel |
| TLV2631IDBV | SOT-23-5 | DBV | VAZI | | TLV2631IDBVR† TLV2631IDBVT‡ | Tape and Reel |
| TLV2631IP | DIP-8 | P | — | | TLV2631IP | Tube |
| Dual without Shutdown | | | | | | |
| TLV2632ID | SOIC-8 | D | — | -40°C to 125°C | TLV2632ID TLV2632IDR | Tube Tape and Reel |
| TLV2632IDGK | MSOP-8 | DGK | AKG | | TLV2632IDGK TLV2632IDGKR | Tube Tape and Reel |
| TLV2632IP | DIP-8 | P | — | | TLV2632IP | Tube |
| Dual with Shutdown | | | | | | |
| TLV2633ID | SOIC-14 | D | — | -40°C to 125°C | TLV2633ID TLV2633IDR | Tube Tape and Reel |
| TLV2633IDGS | MSOP-10 | DGS | AKK | | TLV2633IDGS TLV2633IDGSR | Tube Tape and Reel |
| TLV2633IN | DIP-14 | N | — | | TLV2633IN | Tube |
| Quad without Shutdown | | | | | | |
| TLV2634ID | SOIC-14 | D | — | -40°C to 125°C | TLV2634ID TLV2634IDR | Tube Tape and Reel |
| TLV2634IN | DIP-14 | N | — | | TLV2634IN | Tube |
| TLV2634IPW | TSSOP-14 | PW | — | | TLV2634IPW TLV2634IPWR | Tube Tape and Reel |
| Quad with Shutdown | | | | | | |
| TLV2635ID | SOIC-16 | D | — | -40°C to 125°C | TLV2635ID TLV2635IDR | Tube Tape and Reel |
| TLV2635IN | DIP-16 | N | — | | TLV2635IN | Tube |
| TLV2635IPW | TSSOP-16 | PW | — | | TLV2635IPW TLV2635IPWR | Tube Tape and Reel |

† The SOT23 package devices are only available taped and reeled. The R Suffix denotes quantities (3,000 pieces per reel).

‡ The T Suffix denotes smaller quantities (250 pieces per mini-reel).

1. For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

| | |
|--|--|
| Supply voltage, V_{DD} (see Note 1) | 6 V |
| Differential input voltage, V_{ID} | $\pm V_{DD}$ |
| Input voltage range, V_I (see Note 1) | GND to $V_{DD} - 1$ V |
| Input current, I_I (any input) | ± 10 mA |
| Output current, I_O | ± 40 mA |
| Continuous total power dissipation | See Dissipation Rating Table |
| Operating free-air temperature range, T_A : I-suffix | -40°C to 125°C |
| Maximum junction temperature, T_J | 150°C |
| Storage temperature range, T_{stg} | -65°C to 150°C |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds | 260°C |

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 2: All voltage values, except differential voltages, are with respect to GND.

recommended operating conditions

| | | MIN | MAX | UNIT |
|--|---------------|------------|------------|------------------|
| Supply voltage, V_{DD} | Single supply | 2.7 | 5.5 | V |
| | Split supply | ± 1.35 | ± 2.75 | |
| Common-mode input voltage range, V_{ICR} | | GND | $V_{DD}-1$ | V |
| Operating free-air temperature, T_A | I-suffix | -40 | 125 | $^\circ\text{C}$ |
| Shutdown on/off voltage level‡ | V_{IL} | | 0.4 | V |
| | V_{IH} | 2 | | |

‡ Relative to GND.

electrical characteristics at specified free-air temperature, $V_{DD} = 2.7$ V, 5 V (unless otherwise noted)

dc performance

| PARAMETER | TEST CONDITIONS | T_A | MIN | TYP | MAX | UNIT |
|--|---|---------------------|---------------------|------|---------------|------------------------------|
| V_{IO} Input offset voltage | $V_{IC} = V_{DD}/2$, $V_O = V_{DD}/2$ | TLV2634/5 | 25 $^\circ\text{C}$ | 250 | 3500 | μV |
| | | | Full range | | 4500 | |
| | | 25 $^\circ\text{C}$ | 250 | 4200 | μV | |
| | | Full range | | 5200 | | |
| α_{VIO} Temperature coefficient of input offset voltage | | 25 $^\circ\text{C}$ | | 3 | | $\mu\text{V}/^\circ\text{C}$ |
| CMRR Common-mode rejection ratio | $V_{IC} = \text{GND to } V_{DD}-1$ V | $V_{DD} = 2.7$ V | 25 $^\circ\text{C}$ | 76 | 100 | dB |
| | | | Full range | 67 | | |
| | | 25 $^\circ\text{C}$ | 77 | 100 | | |
| | | Full range | 74 | | | |
| A_{VD} Large-signal differential voltage amplification | $R_L = 2$ k Ω , $V_{O(PP)} = V_{DD}-1$ V | 25 $^\circ\text{C}$ | 90 | 100 | dB | |
| | | Full range | 82 | | | |

electrical characteristics at specified free-air temperature, $V_{DD} = 2.7\text{ V}, 5\text{ V}$ (unless otherwise noted) (continued)

input characteristics

| PARAMETER | TEST CONDITIONS | T_A^\dagger | MIN | TYP | MAX | UNIT |
|--|--|---------------|-----|------|-----|------|
| I_{IO} Input offset current | $V_{IC} = V_{DD}/2,$ $V_O = V_{DD}/2$ | 25°C | | 1 | 50 | pA |
| | | Full range | | | 100 | |
| 25°C | | | | 1 | 50 | |
| | | Full range | | | 200 | |
| $r_{i(d)}$ Differential input resistance | | 25°C | | 1000 | | GΩ |
| $C_{i(c)}$ Common-mode input capacitance | $f = 1\text{ kHz}$ | 25°C | | 12 | | pF |

† Full range is –40°C to 125°C for the I-suffix.

output characteristics

| PARAMETER | TEST CONDITIONS | T_A^\dagger | MIN | TYP | MAX | UNIT | |
|---------------------------------------|--|-------------------------|-----------------------|------------|-------|------|------|
| V_{OH} High-level output voltage | $V_{IC} = V_{DD}/2, I_{OH} = -1\text{ mA}$ | $V_{DD} = 2.7\text{ V}$ | 25°C | 2.6 | 2.67 | V | |
| | | | Full range | | 2.55 | | |
| | | 25°C | $V_{DD} = 5\text{ V}$ | | 4.92 | | 4.98 |
| | | | | Full range | | | 4.9 |
| | $V_{IC} = V_{DD}/2, I_{OH} = -10\text{ mA}$ | $V_{DD} = 2.7\text{ V}$ | 25°C | 2.25 | 2.43 | | |
| | | | Full range | | 2.15 | | |
| | | 25°C | $V_{DD} = 5\text{ V}$ | | 4.7 | | 4.8 |
| | | | | Full range | | | 4.65 |
| V_{OL} Low-level output voltage | $V_{IC} = V_{DD}/2, I_{OL} = 1\text{ mA}$ | $V_{DD} = 2.7\text{ V}$ | 25°C | | 0.03 | 0.1 | mV |
| | | | Full range | | | 0.15 | |
| | | 25°C | $V_{DD} = 5\text{ V}$ | | 0.025 | 0.08 | |
| | | | | Full range | | | |
| | $V_{IC} = V_{DD}/2, I_{OL} = 10\text{ mA}$ | $V_{DD} = 2.7\text{ V}$ | 25°C | | 0.26 | 0.45 | |
| | | | Full range | | | 0.47 | |
| | | 25°C | $V_{DD} = 5\text{ V}$ | | 0.2 | 0.3 | |
| | | | | Full range | | | |
| I_O Output current | $V_{DD} = 2.7\text{ V},$ $V_O = 0.5\text{ V}$ from rail | Sourcing | 25°C | | 14 | mA | |
| | | Sinking | | | 19 | | |
| | $V_{DD} = 5\text{ V},$ $V_O = 0.5\text{ V}$ from rail | Sourcing | | | 28 | | |
| | | Sinking | | | 28 | | |
| I_{OS} Short-circuit output current | Sourcing | $V_{DD} = 2.7\text{ V}$ | 25°C | | 50 | mA | |
| | | $V_{DD} = 5\text{ V}$ | | | 95 | | |
| | Sinking | $V_{DD} = 2.7\text{ V}$ | | | 50 | | |
| | | $V_{DD} = 5\text{ V}$ | | | 95 | | |

† Full range is –40°C to 125°C for the I-suffix.

power supply

| PARAMETER | TEST CONDITIONS | T_A^\dagger | MIN | TYP | MAX | UNIT | |
|--|---|---------------|------|------------|------|------|----|
| I_{DD} Supply current (per channel) | $V_O = V_{DD}/2,$ $\overline{\text{SHDN}} = V_{DD}$ | 25°C | | 730 | 1000 | μA | |
| | | Full range | | | 1350 | | |
| PSRR Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$) | $V_{DD} = 2.7\text{ V}$ to $5.5\text{ V},$ $V_{IC} = V_{DD}/2$ | No load | 25°C | | 70 | 90 | dB |
| | | | | Full range | | 65 | |

† Full range is –40°C to 125°C for the I-suffix.

electrical characteristics at specified free-air temperature, $V_{DD} = 2.7\text{ V}, 5\text{ V}$ (unless otherwise noted)
 (continued)

dynamic performance

| PARAMETER | | TEST CONDITIONS | | T_A^\dagger | MIN | TYP | MAX | UNIT |
|-----------|----------------------------------|---|---|---------------|-----|-----|-----|------------------|
| GBWP | Gain-bandwidth product | $R_L = 2\text{ k}\Omega, C_L = 10\text{ pF}, f = 10\text{ kHz}$ | | 25°C | | 9 | | MHz |
| SR+ | Positive slew rate at unity gain | $R_L = 2\text{ k}\Omega, C_L = 50\text{ pF}$ | $V_{DD} = 2.7\text{ V}, V_{O(PP)} = 1.7\text{ V}$ | | | 6 | | V/ μs |
| | | | $V_{DD} = 5\text{ V}, V_{O(PP)} = 3.5\text{ V}$ | | | 6 | | V/ μs |
| SR- | Negative slew rate at unity gain | $R_L = 2\text{ k}\Omega, C_L = 50\text{ pF}$ | $V_{DD} = 2.7\text{ V}, V_{O(PP)} = 1.7\text{ V}$ | | | 10 | | V/ μs |
| | | | $V_{DD} = 5\text{ V}, V_{O(PP)} = 3.5\text{ V}$ | | | 9.5 | | V/ μs |
| ϕ_m | Phase margin | $R_L = 2\text{ k}\Omega, C_L = 10\text{ pF}$ | | | | 50 | | ° |
| | Gain margin | | | | 20 | | dB | |

† Full range is -40°C to 125°C for the I-suffix.

noise/distortion performance

| PARAMETER | | TEST CONDITIONS | | T_A | MIN | TYP | MAX | UNIT | |
|-----------|--------------------------------------|---|-------------|-------|-----|--------|-----|------|------------------------|
| THD + N | Total harmonic distortion plus noise | $V_{O(PP)} = V_{DD}/2, R_L = 2\text{ k}\Omega, f = 10\text{ kHz}$ | $A_V = 1$ | 25°C | | 0.003% | | | |
| | | | $A_V = 10$ | | | 0.02% | | | |
| | | | $A_V = 100$ | | | 0.095% | | | |
| V_n | Equivalent input noise voltage | $f = 1\text{ kHz}$ | | | | | 50 | | nV/ $\sqrt{\text{Hz}}$ |
| | | $f = 10\text{ kHz}$ | | | | | 30 | | nV/ $\sqrt{\text{Hz}}$ |
| I_n | Equivalent input noise current | $f = 1\text{ kHz}$ | | | | | 0.9 | | fA/ $\sqrt{\text{Hz}}$ |

shutdown characteristics

| PARAMETER | | TEST CONDITIONS | | T_A^\dagger | MIN | TYP | MAX | UNIT |
|-----------------------|--|--|-------------------------|---------------|-----|-----|-----|---------------|
| $I_{DD(\text{SHDN})}$ | Supply current, per channel in shutdown mode (TLV2630, TLV2633, TLV2635) | $\overline{\text{SHDN}} = 0.4\text{ V}$ | | 25°C | | 4 | 17 | μA |
| | | | | Full range | | | 19 | μA |
| $t_{(\text{on})}$ | Amplifier turnon time ‡ | $R_L = 2\text{ k}\Omega, C_L = 10\text{ pF}$ | $V_{DD} = 2.7\text{ V}$ | 25°C | | 4.5 | | μs |
| | | | $V_{DD} = 5\text{ V}$ | | | 1.5 | | μs |
| $t_{(\text{off})}$ | Amplifier turnoff time ‡ | | | | | | 200 | |

† Full range is -40°C to 125°C for the I-suffix.

‡ Disable time and enable time are defined as the interval between application of the logic signal to $\overline{\text{SHDN}}$ and the point at which the supply current has reached half its final value.

DISSIPATION RATING TABLE

| PACKAGE | Θ_{JC} (°C/W) | Θ_{JA} (°C/W) | $T_A \leq 25^\circ\text{C}$ POWER RATING | $T_A = 125^\circ\text{C}$ POWER RATING |
|------------|-------------------------|-------------------------|---|---|
| D (8) | 38.3 | 176 | 710 mW | 142 mW |
| D (14) | 26.9 | 122.3 | 1022 mW | 204.4 mW |
| D (16) | 25.7 | 114.7 | 1090 mW | 218 mW |
| DBV (5) | 55 | 324.1 | 385 mW | 77.1 mW |
| DBV (6) | 55 | 294.3 | 425 mW | 85 mW |
| DGK (8) | 54.2 | 259.9 | 481 mW | 96.1 mW |
| DGS (10) | 54.1 | 259.7 | 485 mW | 97 mW |
| N (14, 16) | 32 | 78 | 1600 mW | 320.5 mW |
| P (8) | 41 | 104 | 1200 mW | 240.4 mW |
| PW (14) | 29.3 | 173.6 | 720 mW | 144 mW |
| PW (16) | 28.7 | 161.4 | 774 mW | 154.9 mW |

TYPICAL CHARACTERISTICS

Table of Graphs

| | | | FIGURE |
|----------------|--|------------------------------|--------|
| V_{IO} | Input offset voltage | vs Common-mode input voltage | 1, 2 |
| CMRR | Common-mode rejection ratio | vs Frequency | 3 |
| V_{OH} | High-level output voltage | vs High-level output current | 4, 6 |
| V_{OL} | Low-level output voltage | vs Low-level output current | 5, 7 |
| I_{DD} | Supply current | vs Supply voltage | 8 |
| I_{DD} | Supply current | vs Free-air temperature | 9 |
| PSRR | Power supply rejection ratio | vs Frequency | 10 |
| A_{VD} | Differential voltage amplification & phase | vs Frequency | 11 |
| | Gain-bandwidth product | vs Supply voltage | 12 |
| | | vs Free-air temperature | 13 |
| SR | Slew rate | vs Supply voltage | 14 |
| | | vs Free-air temperature | 15, 16 |
| ϕ_m | Phase margin | vs Load capacitance | 17 |
| V_n | Equivalent input noise voltage | vs Frequency | 18 |
| | Crosstalk | vs Frequency | 19 |
| | Voltage-follower large-signal pulse response | | 20 |
| | Voltage-follower small-signal pulse response | | 21 |
| $I_{DD(SHDN)}$ | Shutdown supply current | vs Free-air temperature | 22 |
| $I_{DD(SHDN)}$ | Shutdown supply current | vs Supply voltage | 23 |
| $I_{DD(SHDN)}$ | Shutdown supply current/output voltage | vs Time | 24 |

TYPICAL CHARACTERISTICS

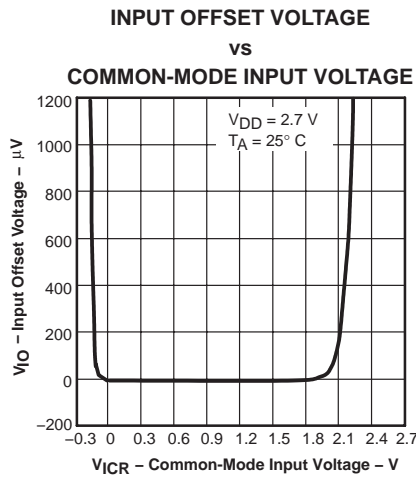


Figure 1

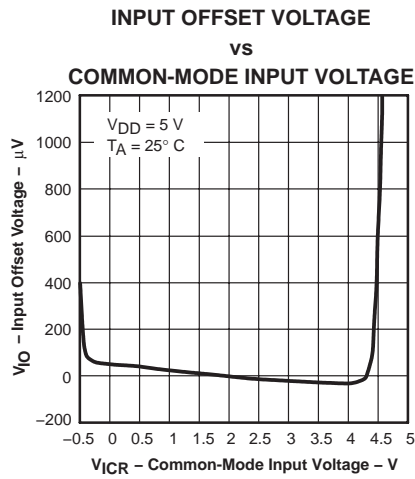


Figure 2

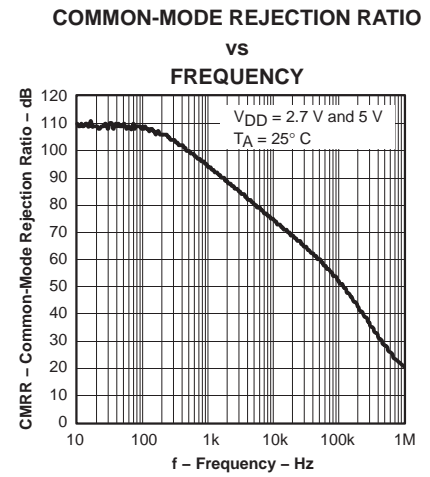


Figure 3

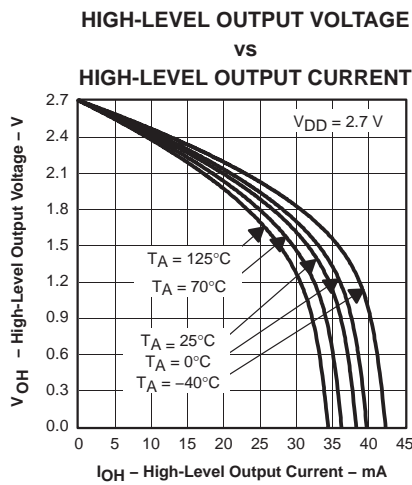


Figure 4

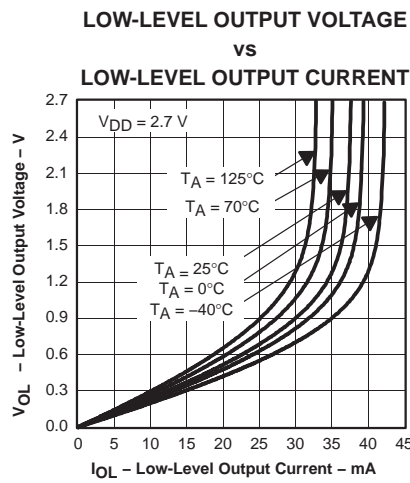


Figure 5

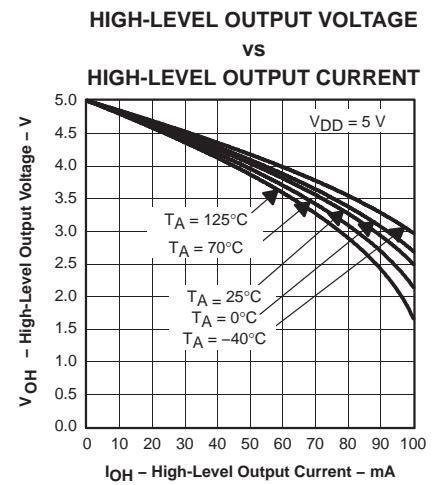


Figure 6

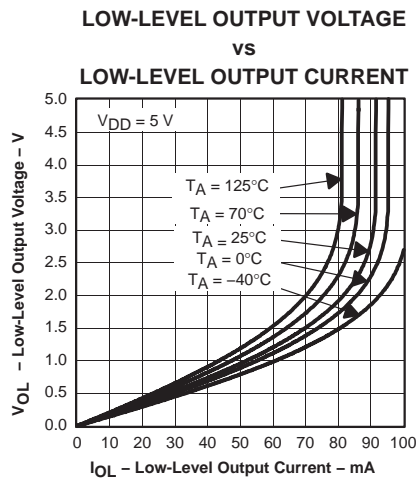


Figure 7

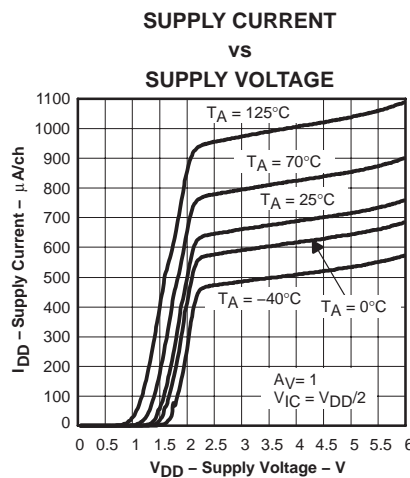


Figure 8

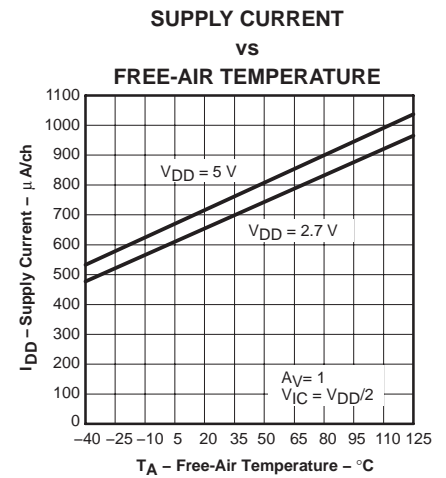


Figure 9

TYPICAL CHARACTERISTICS

POWER SUPPLY REJECTION RATIO

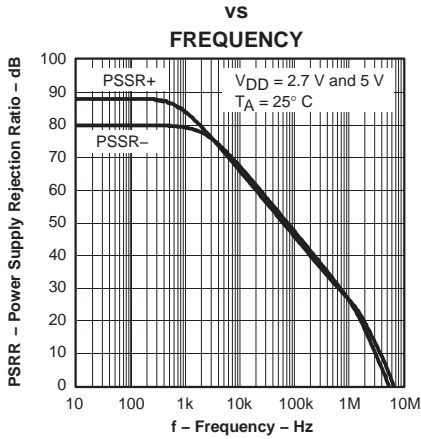


Figure 10

DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE

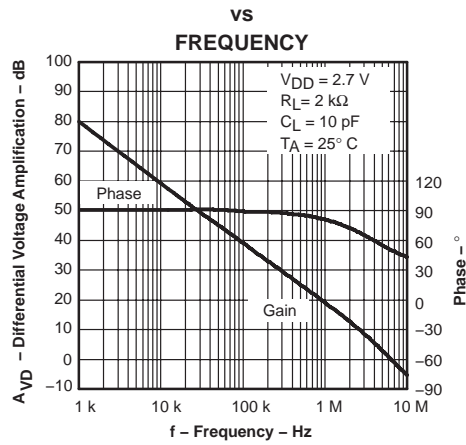


Figure 11

GAIN-BANDWIDTH PRODUCT

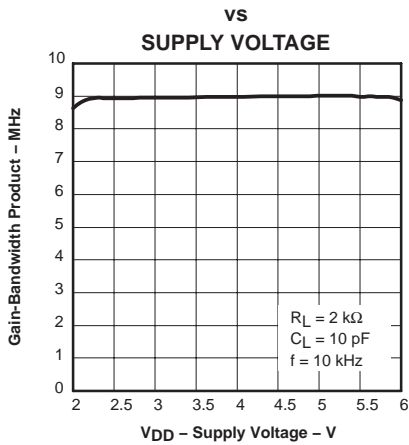


Figure 12

GAIN-BANDWIDTH PRODUCT

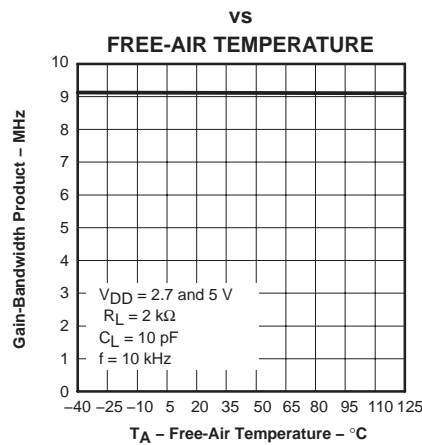


Figure 13

SLEW RATE

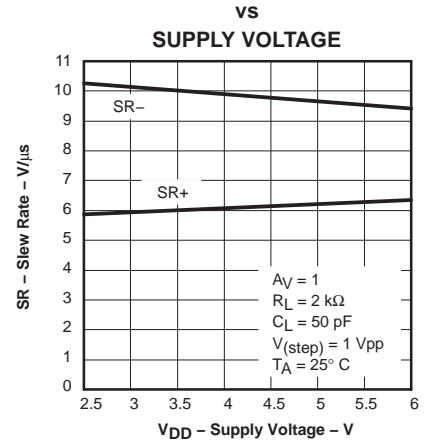


Figure 14

SLEW RATE

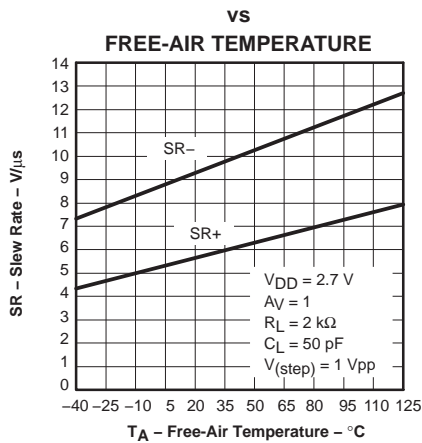


Figure 15

SLEW RATE

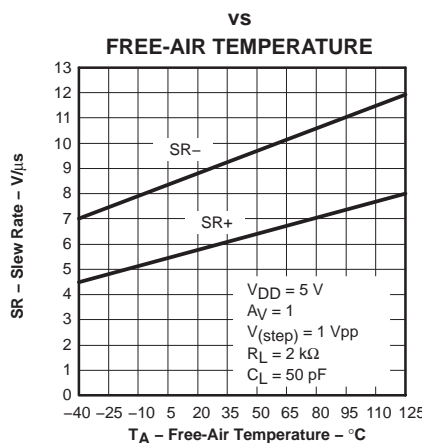


Figure 16

PHASE MARGIN

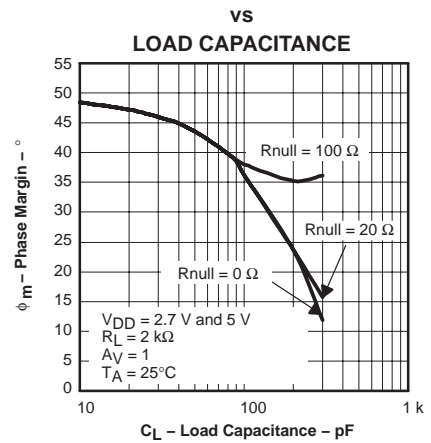


Figure 17

TYPICAL CHARACTERISTICS

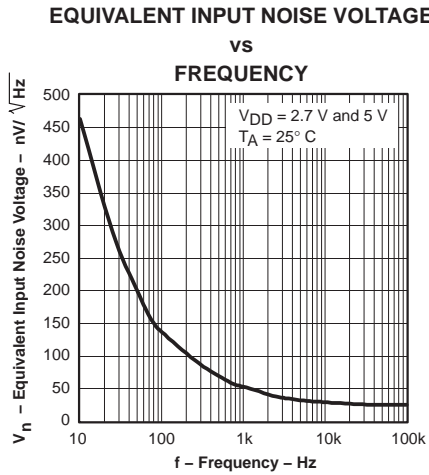


Figure 18

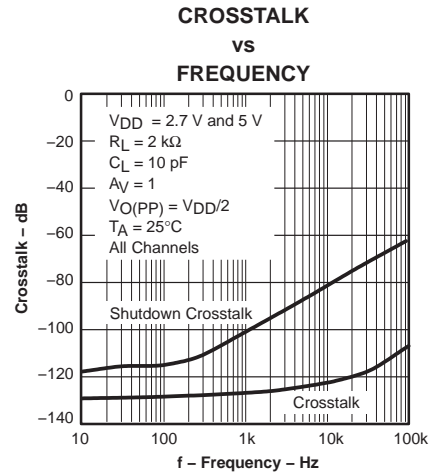


Figure 19

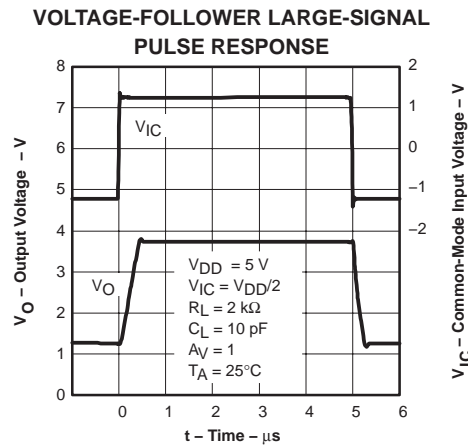


Figure 20

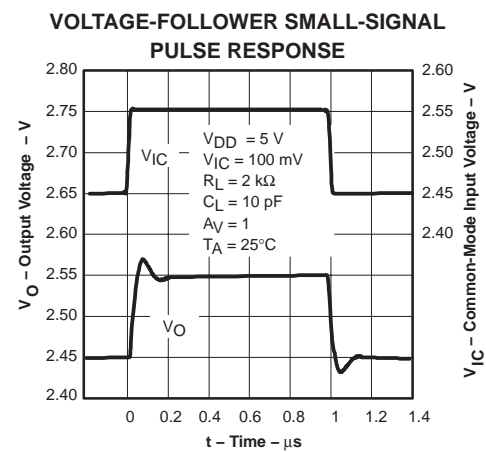


Figure 21

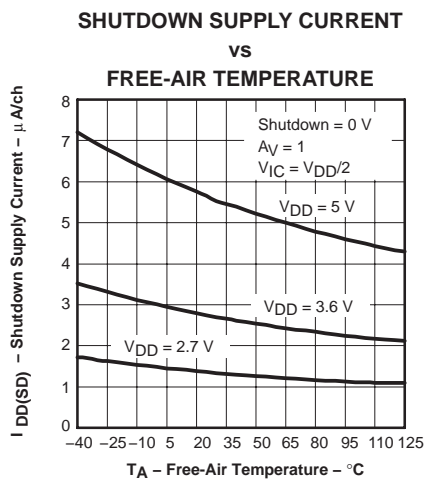


Figure 22

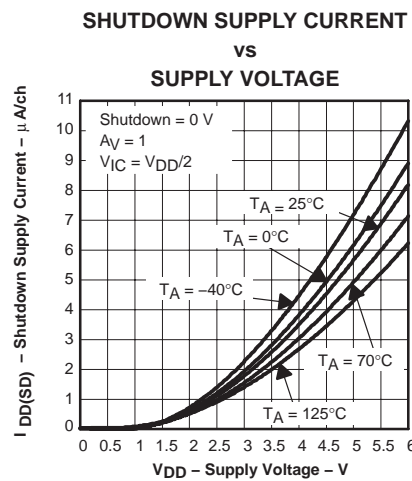


Figure 23

TYPICAL CHARACTERISTICS

SHUTDOWN SUPPLY CURRENT / OUTPUT VOLTAGE vs TIME

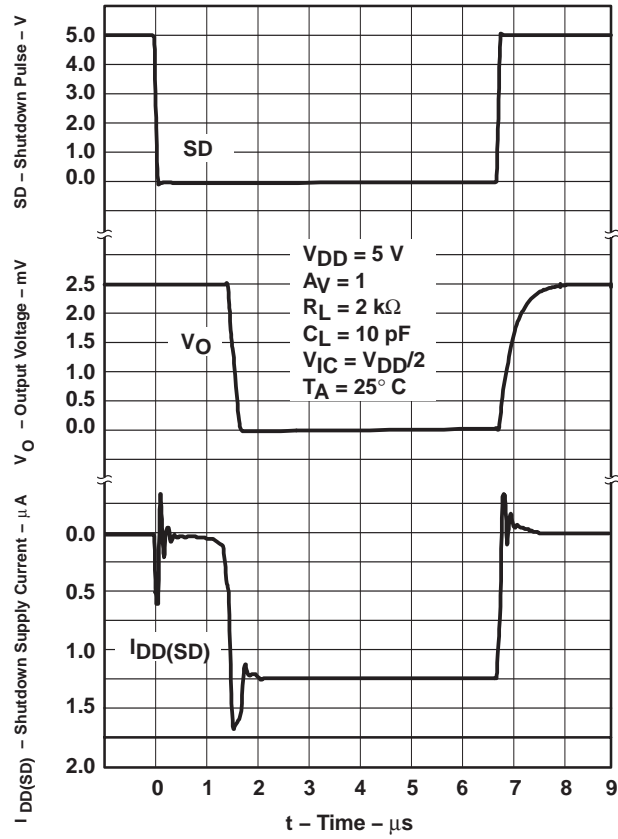
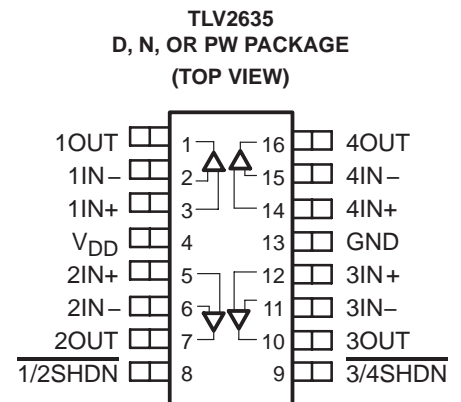
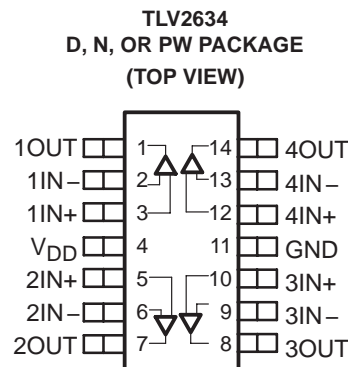
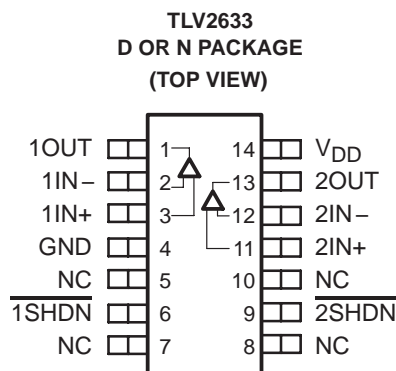
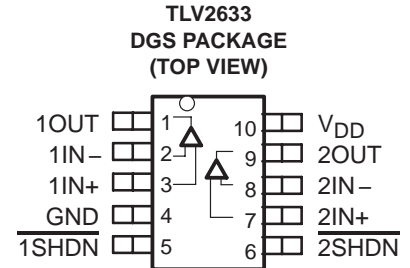
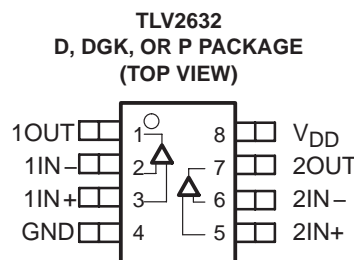
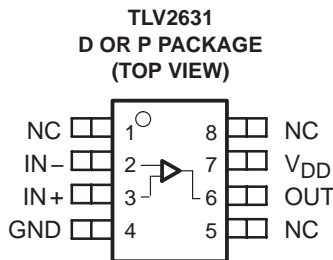
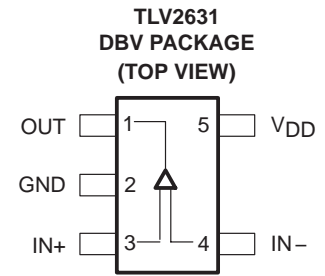
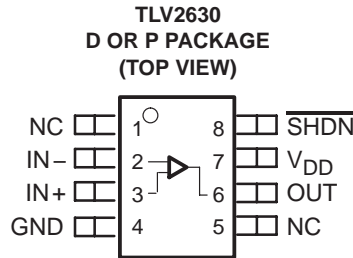
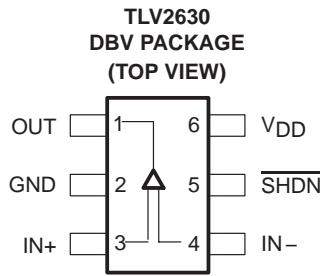


Figure 24

TLV263x PACKAGE PINOUTS



NC – No internal connection

PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ |
|------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|------------------|------------------------------|
| TLV2630IDBVR | ACTIVE | SOT-23 | DBV | 6 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2630IDBVRG4 | ACTIVE | SOT-23 | DBV | 6 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2631IDBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2631IDBVRG4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2631IDBVT | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2631IDBVTG4 | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2632ID | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2632IDG4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2632IDGKR | ACTIVE | MSOP | DGK | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2632IDGKRG4 | ACTIVE | MSOP | DGK | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2632IDR | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2632IDRG4 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2633IDGSR | ACTIVE | MSOP | DGS | 10 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2633IDGSRG4 | ACTIVE | MSOP | DGS | 10 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2634ID | ACTIVE | SOIC | D | 14 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2634IDG4 | ACTIVE | SOIC | D | 14 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2634IPWR | ACTIVE | TSSOP | PW | 14 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2634IPWRG4 | ACTIVE | TSSOP | PW | 14 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2635ID | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TLV2635IDG4 | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TLV2630IDBVR | SOT-23 | DBV | 6 | 3000 | 180.0 | 9.0 | 3.15 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2631IDBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 9.0 | 3.15 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2631IDBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 9.0 | 3.15 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2632IDGKR | MSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLV2632IDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLV2633IDGSR | MSOP | DGS | 10 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLV2634IPWR | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 7.0 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS

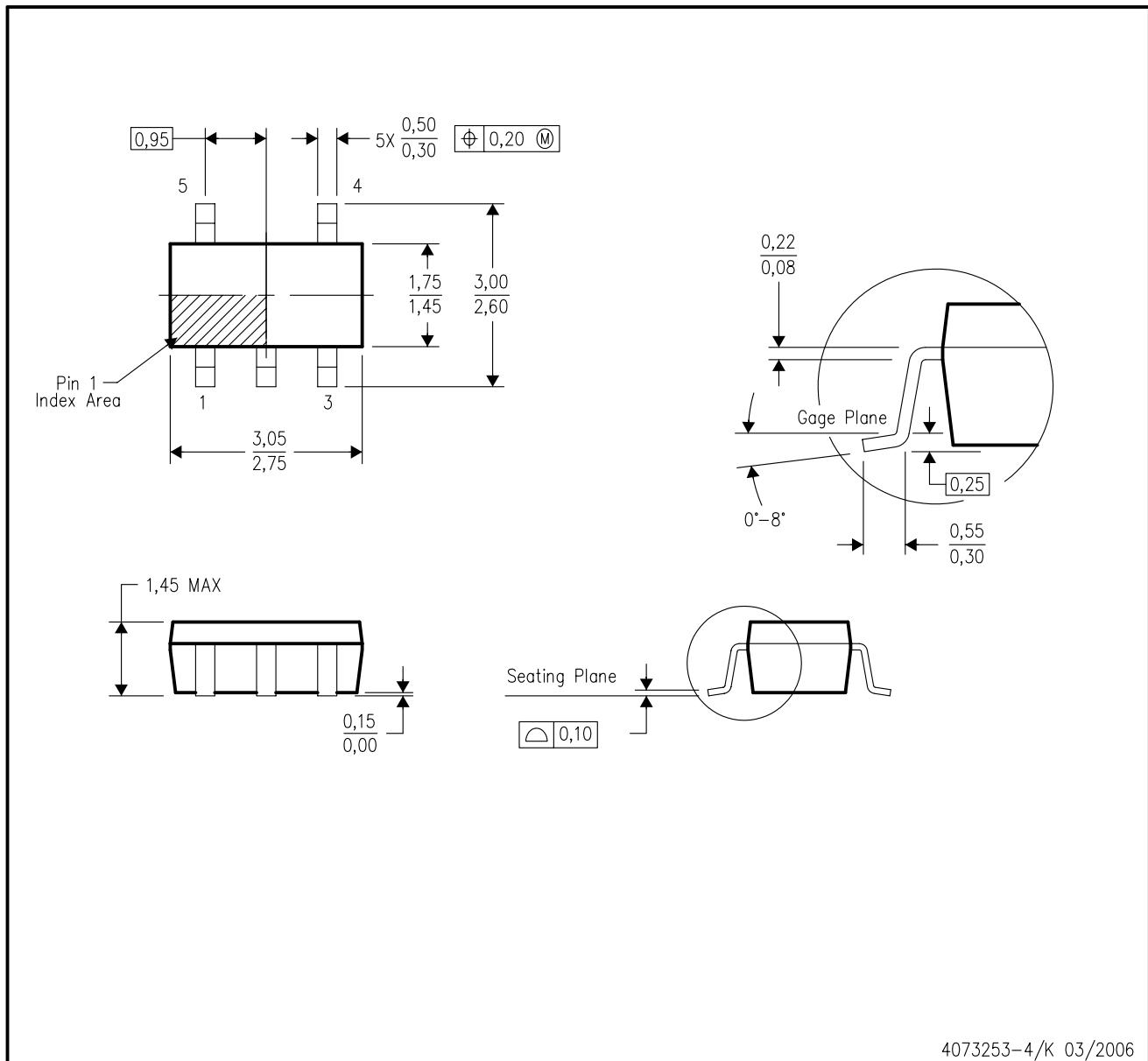


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TLV2630IDBVR | SOT-23 | DBV | 6 | 3000 | 182.0 | 182.0 | 20.0 |
| TLV2631IDBVR | SOT-23 | DBV | 5 | 3000 | 182.0 | 182.0 | 20.0 |
| TLV2631IDBVT | SOT-23 | DBV | 5 | 250 | 182.0 | 182.0 | 20.0 |
| TLV2632IDGKR | MSOP | DGK | 8 | 2500 | 358.0 | 335.0 | 35.0 |
| TLV2632IDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| TLV2633IDGSR | MSOP | DGS | 10 | 2500 | 358.0 | 335.0 | 35.0 |
| TLV2634IPWR | TSSOP | PW | 14 | 2000 | 346.0 | 346.0 | 29.0 |

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - Falls within JEDEC MO-178 Variation AA.

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



4040064/F 01/97

- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-153

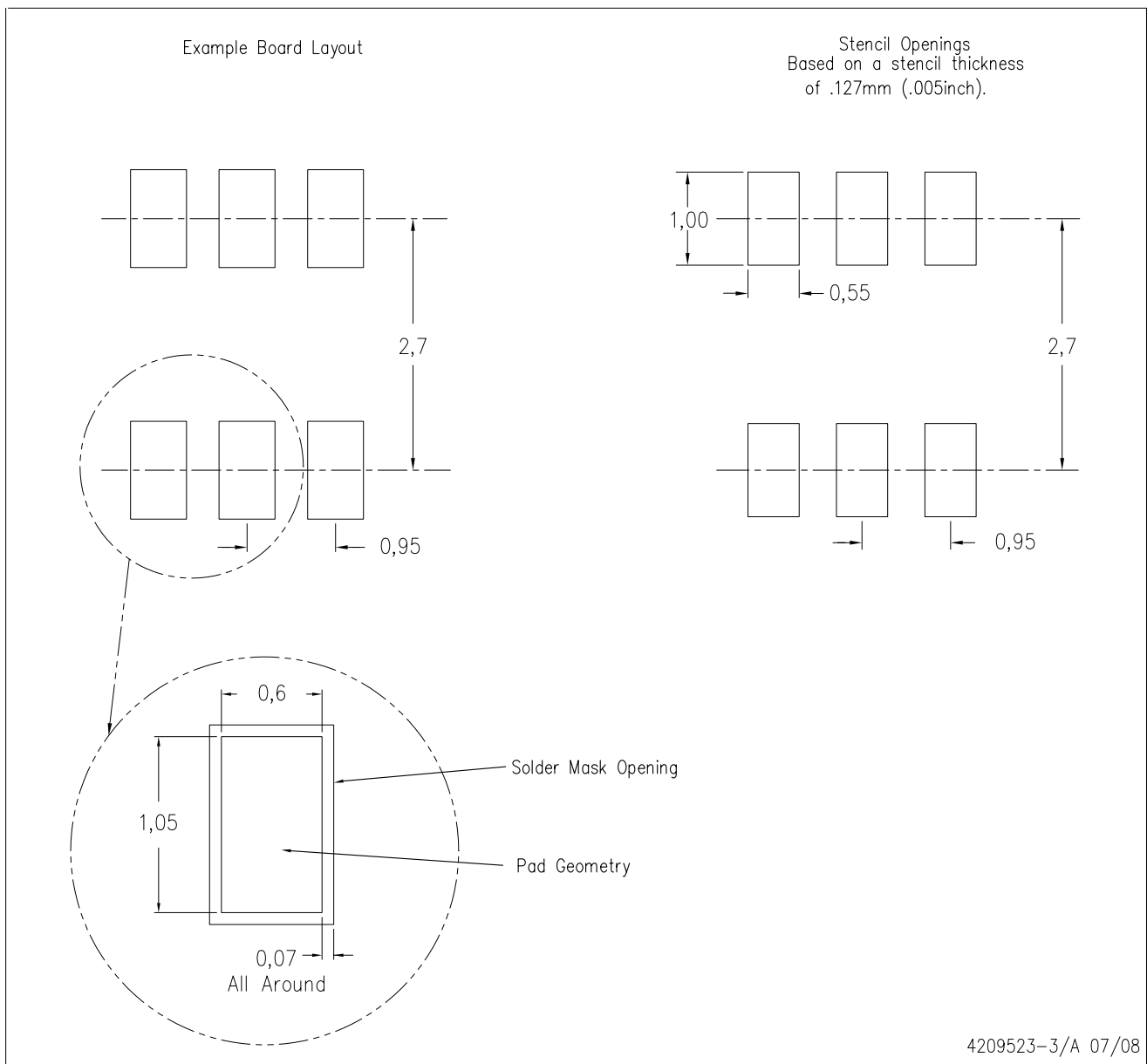
DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



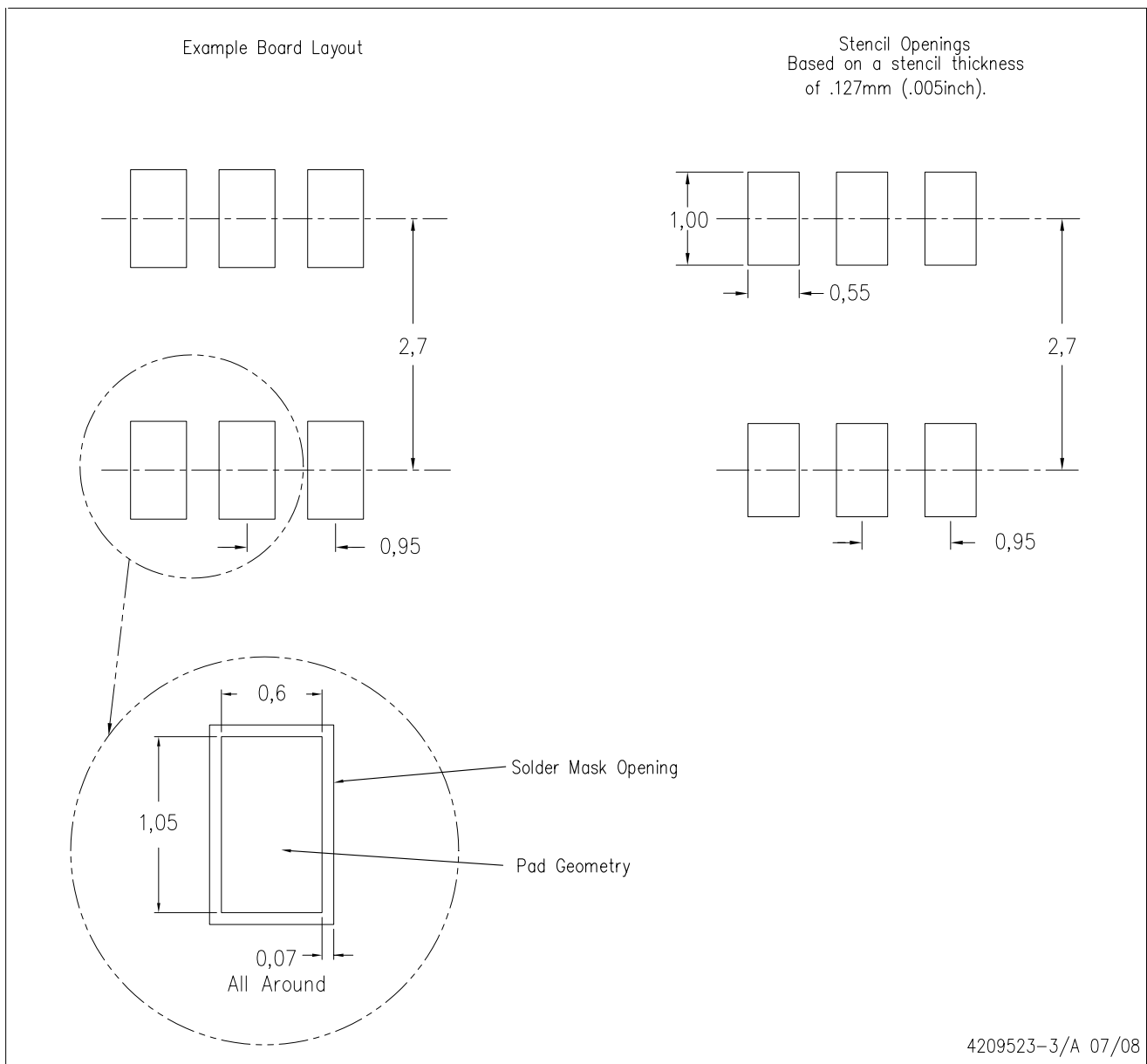
- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- \triangleleft Falls within JEDEC MO-178 Variation AB, except minimum lead width.

DBV (R-PDSO-G6)



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - D. Publication IPC-7351 is recommended for alternate designs.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

DBV (R-PDSO-G6)



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - D. Publication IPC-7351 is recommended for alternate designs.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
 - E. Falls within JEDEC MO-187 variation AA, except interlead flash.

D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
 - E. Reference JEDEC MS-012 variation AC.

D(R-PDSO-G16)

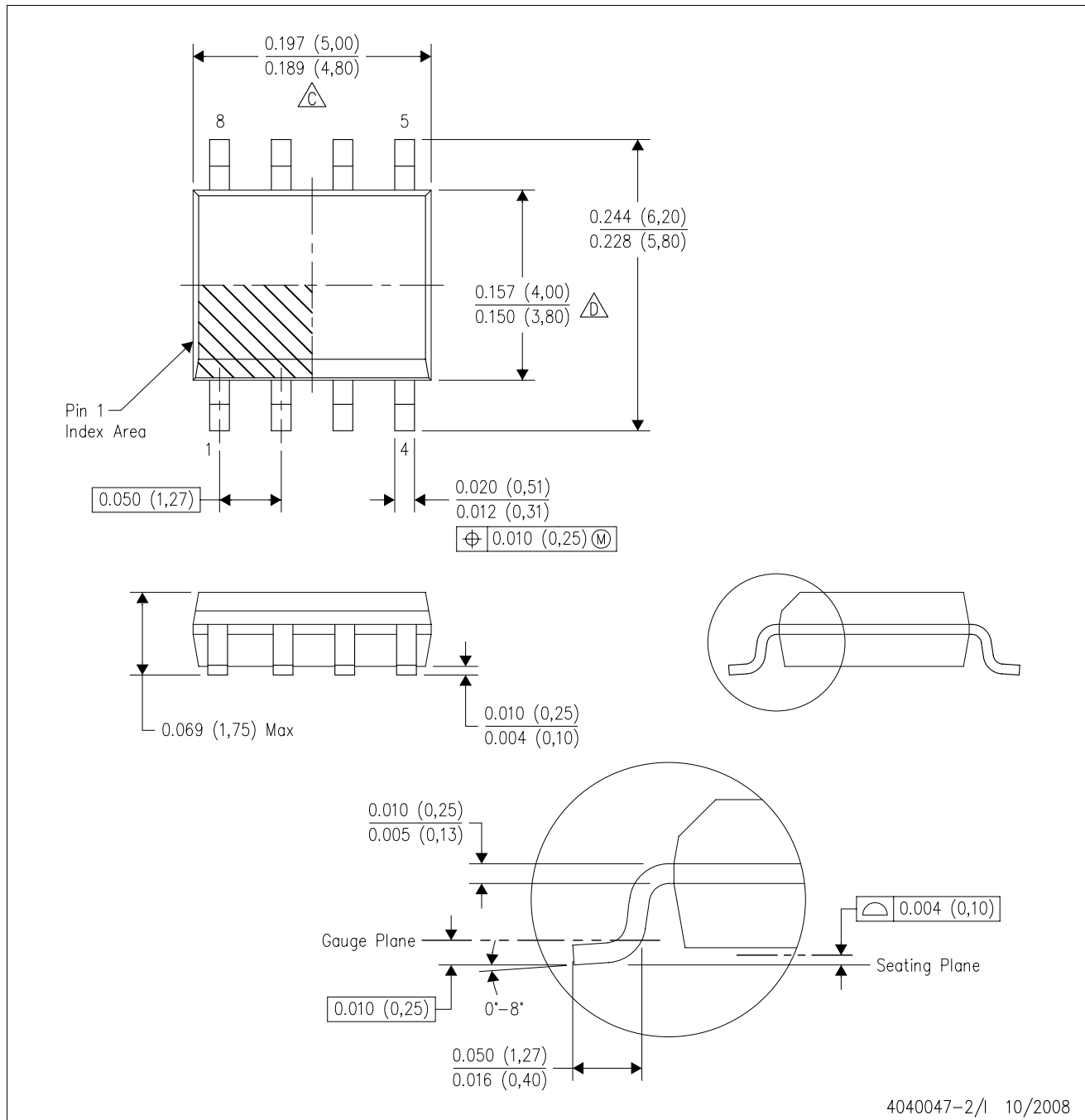


4209373/A 03/08

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Refer to IPC7351 for alternate board design.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

D (R-PDSO-G8)

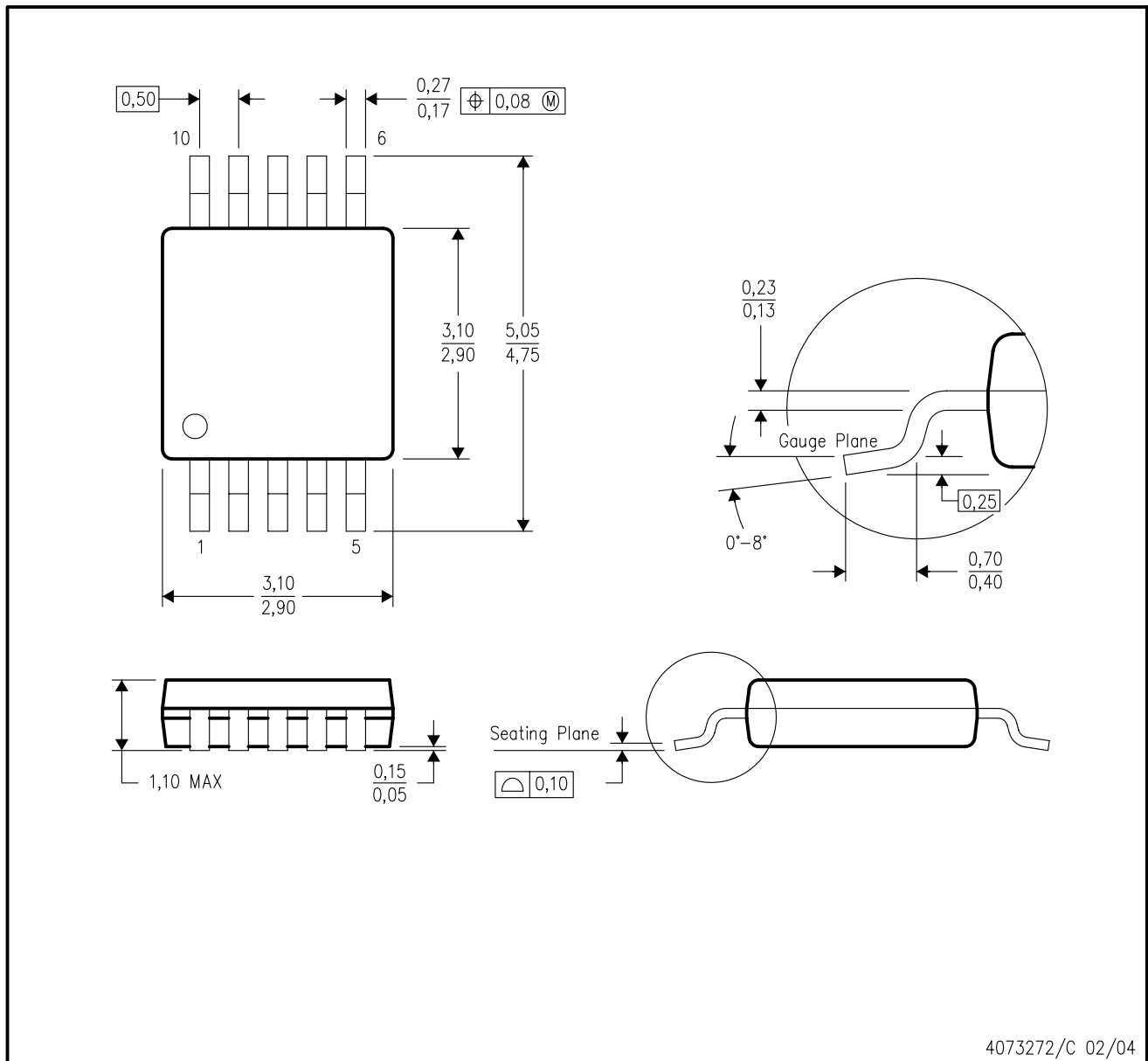
PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
 - E. Reference JEDEC MS-012 variation AA.

DGS (S-PDSO-G10)

PLASTIC SMALL-OUTLINE PACKAGE



4073272/C 02/04

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion.
 - D. Falls within JEDEC MO-187 variation BA.

D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
 - E. Reference JEDEC MS-012 variation AB.

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